

Form PTO-1449 (modified) List of Patents and Publications For Applicant's Information Disclosure Statement (Use several sheets if necessary)	ATTY. DKT. NO. 5310-03900	SERIAL NO. Unknown
	APPLICANT: Skotnicki et al.	GROUP: Unknown
	FILING DATE: Herewith	10/018179

U.S. PATENT DOCUMENTS

EXAM. INITIALS	REF. DES.	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
H?	A1	5,371,394	12/1994	Ma et al.	—	—	

FOREIGN PATENT DOCUMENTS

EXAM. INITIALS	REF. DES.	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES/NO
H?	A2	06 318698	11/1994	JP	—	—	
H?	A3	0 763 855	03/1997	EP	—	—	

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

H?	A4	Hajime Kurata et al: "Self-Aligned Control of Threshold Voltages in Sub-0.2- μ m MOSFET's" IEEE Transactions on Electron Devices, Vol. 45, no. 10, US, New-York, NY: IEEE, October 1998, pages 2161-2166, XP000786856 ISBN: 0018-9383					
H?	A5	Yoshinori Okumura et al: "Source-to-Drain Nonuniformly Doped Channel (NUDC) MOSFET Structures for High Current Drivability and Threshold Voltage Controllability" IEEE Transactions on Electron Devices, Vol. 39, no. 11, US, New-York, NY: IEEE, November 1992, pages 2541-2552, XP000321695 ISBN: 0018-9383					

EXAMINER:

DATE CONSIDERED:

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the patent owner.

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